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Andreev and Single-Particle Tunneling Spectra of Underdoped Cuprate Superconductors

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We study tunneling spectroscopy between a normal metal and an underdoped cuprate superconductor modeled by a phenomenological theory in which the pseudogap is a precursor to the undoped Mott insulator. In the low barrier tunneling limit, the spectra are enhanced by Andreev reflection only within a voltage region of the small superconducting energy gap. In the high barrier tunneling limit, the spectra show a large energy pseudogap associated with single particle tunneling. Our theory semi-quantitatively describes the two gap behavior observed in tunneling experiments.

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It has long been argued that the highly anomalous pseudogap phase of underdoped (UD) cuprates holds the key to the physics of high \( T_c \) superconductors [1–4]. A variety of models have been proposed to describe this phase. At present a consensus is lacking and the merits of the different models are being vigorously debated. Some models propose the partial truncation of the Fermi surface (FS) in the pseudogap phase is due to the presence of a long range order, which breaks translational symmetry. However, in the absence of experimental evidence [5], models without this property have gained traction. These in turn can be divided into two classes. One emphasizes the reduction of the superconducting (SC) \( T_c \) by strong phase fluctuations due to the reduced superfluid density in UD cuprates. This allows the larger SC energy gaps, which in the \( d \)-wave form are maximal in the antinodal directions on the FS, to remain finite at temperatures \( T > T_c \) due to preformed Cooper pairs but without off-diagonal long range order [6]. Nernst effect and diamagnetism experiments confirm the presence of SC fluctuations in an extended temperature range above \( T_c \) in the UD region of the phase diagram but the range ends substantially below the temperature scale of the onset of pseudogap behavior [7,8]. Alternative models interpret the anomalous properties of the pseudogap phase as precursor to the Mott insulator at zero doping [1], and describe the SC gap as a much lower energy scale.

Andreev tunneling has been proposed as a tool to distinguish between SC pairing fluctuations and precursor insulating in the pseudogap phase in an early paper by Deutscher [9]. In the Andreev tunneling process, an electron tunnels from a metal into a superconductor in the form of a Cooper pair and a reflected hole [10,11], which unambiguously measures the SC gap. It was pointed out that the voltage (or energy) scale in Andreev tunneling experiments on UD cuprates in the pseudogap phase [12] was substantially below that observed in the single particle tunneling experiments. The two voltage scales, however, were the same in the overdoped (OD) region. This led Deutscher to conclude in his review article that “the balance was tilted somewhat against the preformed pairs scenario” [13]. The opposite conclusion, namely, that the higher pseudogap energy scale reflects the pairing strength while a second lower scale, the SC condensation energy, was argued for in a later review by Hufner and co-workers which examined many experimental results using different techniques [14]. To make progress in this debate one needs to move beyond qualitative arguments about individual experiments and to more explicit models which can be used to consistently analyze a whole range of experiments.

In this Letter, we study tunneling spectroscopy between a normal metal and UD SC cuprates, where the UD state is modeled by a phenomenological theory of Yang, Rice, and Zhang (YRZ) [15], which has been successfully applied to explain many experiments. In the low barrier or transparent tunneling limit, Andreev reflection provides an additional conducting channel. We find that the tunneling conductivity is enhanced only within a voltage region of the small SC gap. In the high barrier tunneling limit, the Andreev process is diminished. Tunneling is dominated by the single particle process, and the calculated spectroscopy shows a large pseudogap. Our theory is in good agreement with the experiments, and provides a semi-quantitative description of the two gap scenario.

In the YRZ model, a single particle propagator in 2D was proposed for the pseudogap phase [15]. The model was inspired by an analysis by Konik, Rice, and Tsvelik [16] of a 2D array of lightly doped two-leg Hubbard ladders, and influenced by the functional renormalization group results at weak to moderate interaction strength [17] and by analyses of Anderson’s resonant valence bond (RVB) proposal [18–20]. In this theory, the single particle...
gap at the antinodes is controlled by the RVB gap which truncates the full FS into four pockets centered on the nodal directions. Such hole pockets finally evolve into large FS in OD with a vanishing RVB gap. Typical FS of the model in UD and OD are shown in Fig. 1(a). The d-wave SC energy gap opens up primarily on the Fermi pockets. The ansatz of the pseudogap as an insulating antinodal gap as proposed in the YRZ model is supported by recent numerical calculations on the 2D Hubbard model using cluster dynamical mean field theory [21].

This phenomenological propagator gives a consistent description [15] of angle resolved photoemission spectroscopy (ARPES) experiments which followed the evolution of the FS from four disconnected Fermi nodal arcs in UD to the full FS in OD cuprates [22]. It also explains a range of other spectroscopic measurements [23], e.g., the particle-hole asymmetry observed in ARPES [24], angle integrated photoemission electron spectroscopy experiments measuring the doping, x, dependence of the density of states (DOS) [25] and scanning tunneling microscopy (STM) measurements of the coherent Bogoliubov quasiparticle dispersion at low temperatures [26]. The YRZ form was also used by Carbote, Nicol, and co-workers to successfully describe the T and x dependence of a wide range of properties in the pseudogap phase including specific heat [27], optical conductivity [28], London penetration depth [29], and symmetry-dependent Raman scattering spectra [30]. The latter was also analyzed in a similar way by Valenzuela and Bascones [31].

In the YRZ model [15], the incoherent part of the single particle Green’s function contributes a smooth spectral background with a tiny real component at low energies, and the coherent part reads

\[ G^0(k, \omega) = g_i \frac{1}{(\omega - \epsilon_k - \Sigma^0(k, \omega))} \]

where \[ g_i = 2x/(1 + x) \] is a renormalization factor [19,20], \[ x \] is the doping concentration. We use the result from the renormalized mean field theory for the RVB state as the “bare” dispersion \[ \epsilon_k \] [32]. The self-energy \[ \Sigma^0 \] is zero at OD (\[ x > x_c = 0.2 \]). At UD (\[ x < x_c \]), \[ \Sigma^0(k, \omega) = [\Delta_k^{RVB} / (\omega + \epsilon_k^0)] + [\Delta_k^{RVB} / (1 - x/x_c) (\cos k_x - \cos k_y)] \]

and \[ \Delta_k^{RVB} = \Delta_0 (1 - x/x_c)(\cos k_x - \cos k_y) \], with \[ \Delta_0 = 0.3 \]. All energies are in units of \[ \hbar \omega_0 (= 0.3 \text{ eV}) \]. Note that \[ \epsilon_k^0 = 0 \] at the antiferromagnetic reduced Brillouin zone boundary, where the umklapp scattering is strongest [17]. Equation (1) predicts four Fermi pockets in the pseudogap phase as shown in Fig. 1(a), consistent with the recent laser ARPES data [33].

We consider a d-wave SC gap function, \[ \Delta_k^c = \Delta_0^c (\cos k_x - \cos k_y) \] for the states around the FS within a small energy shell, \( \pm \Delta \). Several previous works proposed a similar SC pairing form for the YRZ model [15,23,29]. We choose \( \Delta_0^c = 0.08 \) for UD (\[ x = 0.1 \]), and \[ \Delta_0^c = 0.04 \] for OD (\[ x = 0.25 \]). These gap parameters lead to the SC gap \( \Delta_x \) (maximum \( \mid \Delta_x^c \mid \) on the FS) comparable to those observed in the Andreev reflection (\( \sim 15 \) and 21 meV, respectively) [12], and to those reported in recent STM data [26]. The Green’s functions for the SC state in UD and OD are,

\[ G_{UD}^{SC}(k, \omega) = g_i \sum_{i=1,2} Z_{k,i} \frac{\omega + E_{k,i} \tau_z - \Delta_{k,i}^{SC} \tau_x}{\omega^2 - E_{k,i}^2 - (\Delta_{k,i}^{SC})^2}, \]

\[ G_{OD}^{SC}(k, \omega) = g_i \frac{\omega + \epsilon_k \tau_z - \Delta_{k}^{SC} \tau_x}{\omega^2 - \epsilon_k^0 - (\Delta_{k}^{SC})^2}, \]

where \( \tau_x/\tau_z \) are the Pauli matrices, and \[ i = 1, 2 \] denotes the lower and higher energy quasiparticle bands given by Eq. (1) for the UD region with spectral weight \[ g_i Z_{k,i} = g_i (1 \pm \xi_k^c / E_k^0) / 2 \] and dispersion \[ E_{k,i} = \xi_k^c \pm E_k^0 \], where \( \xi_k^c = (\epsilon_k^0 - E_k^0) / 2 \), and \[ E_k^0 = \sqrt{[\xi_k^c]^2 + [\Delta_k^{RVB}]^2} \]. \[ G_{OD}^{SC} \] has a BCS form. In the UD region, the quasiparticle energy of the band \[ i = 2 \] is well above the chemical potential, which justifies our choice \( \Delta_{k,z}^c = 0 \). In Fig. 1(b), we show DOS for the normal and SC states from Eqs. (1) and (2) of the model, at \[ x = 0.25 \] (OD) and \[ x = 0.1 \] (UD).

We use the Keldysh formalism to study the tunneling conductivity of a normal metal, superconducting state of cuprates (NS) junction, consisting of a normal metal lead at the left and a SC lead at the right as shown in Fig. 2. We approximate the connection area or line interface as a scattering center. The tunneling of an electron from the left (L) to the right (R) via the scattering center can be described by the hybridization Hamiltonian, \[ H' = \sum_{\alpha=L,R} \sum_{k,a} t_{\alpha k,a} c_{k,a}^d + \text{H.c.} \] with \( c_{k,a} \) and \( d \) the electron annihilation operators at left \( \alpha = L, R \) and on scattering center, respectively. We assume \( t_{\alpha k}^a = t_{\alpha k}^a \). In the tunneling process, \( k \) is conserved, and the total current is given by [34–36], with \( h = 1 \),

\[ I = \sum_{k < \omega} e \int d\omega' \frac{d\xi_k}{2\pi} [T_N^{k}(k, \omega) f^{L}(\omega + seV) - f^{R}(\omega)] + T_A(k, \omega)[f_{L}^{inc}(\omega - seV) - f_{L}^{inc}(\omega - seV)], \]
The normal state is a metal with a full FS [see the T
scatter center]. Spin rotational invariance leads to
ductor side given by Eqs. (1) and (2) at their edges to the
energies $G_{c}^{s} = \frac{1}{2}\left(\omega + \Sigma^{L}(k_{s}) - \Sigma^{R}(k_{s})\right)$ is the
Green’s function in the scattering center [37]. The self
generates $\Sigma^{L}(k_{s}) = \frac{1}{2}\left(\omega - \Sigma^{L}(k_{s}) - \Sigma^{R}(k_{s})\right)$ and lifetime broadening
$\Gamma^{L}(k_{s}) = i\left[\Sigma^{L}(k_{s}) - \Sigma^{L}(k_{s})\right]$, with $G_{c}^{s}(k_{s})$ the
Green’s functions on the metal side or on the superconductor side given by Eqs. (1) and (2) at their edges to the scattering center. Spin rotational invariance leads to $T_{N}^{+}(\omega) = T_{N}(\omega)$ and $T_{A}(\omega) = T_{A}(\omega)$.

The conductance at zero temperature is given by

$$\sigma_{s}(eV) = \int_{-\pi/2}^{\pi/2} \frac{dk_{s}}{2\pi} e^{2} \sum_{s=\pm} \left[T_{N}^{+}(k_{s}, seV) + 2T_{A}(k_{s}, seV)\right].$$

We consider tunneling along an antinodal direction of the CuO$_2$ plane, and assume a parabolic dispersion in the normal metal, $\epsilon_{k} = (k^{2} - k_{F}^{2})/2m$, setting $k_{F} = \pi/2$, $m = \pi/2$ in units of $1/t_{0}$.

We now discuss the tunneling conductance in our model and compare with experiment. We choose $t_{L} = \sqrt{g_{L}t^{R}}$, and a small but finite broadening $\delta$, appearing in frequency $\omega \rightarrow \omega + i\delta$. There are two parameter regions in the tunneling. Large $t^{R}/L$ corresponds to low barrier or transparent tunneling, where Andreev reflection is substantial within the SC gap $\Delta_{s}$. Simultaneously a large scattering rate $\Gamma^{R}/L$, leads to a smooth $\sigma_{s}$. Small $t^{R}/L$ corresponds to high barrier tunneling, where the Andreev reflection is strongly suppressed, and single particle tunneling process dominates.

The OD case is similar to a $d$-wave BCS superconductor. The normal state is a metal with a full FS [see the (red) curve in Fig. 1(a)] and the RVB gap vanishes. The conductance in the transparent limit is shown in Fig. 3(a). There is a marked enhancement of the conductivity $\sigma_{s}$ over $\sigma_{s}$ within the SC gap, which is “universal” in this limit. Note that the detailed shape of $\sigma_{s}$ depends strongly on the parameters in the suppression of the single particle tunneling affected by the Andreev reflection. The conductance in the high barrier limit is shown in Fig. 3(b), where $\sigma_{s}$ follows closely the normal state DOS in Fig. 1(b1), and $\sigma_{s}$ is similar to the single particle spectra for the $d$-wave SC gap, while $\sigma_{s}^{L}$ is vanishingly small. $\sigma_{s}$ in our theory agrees well with STM data [38].

For UD, there are two energy scales, a larger RVB gap or pseudogap and a smaller SC gap $\Delta_{s}$. We expect two distinct energy scales in the tunneling conductance. $\sigma_{s}$ in the transparent region is plotted in Fig. 4(a). The contribution from Andreev reflection is substantial within the SC gap on the FS. $\sigma_{s}$ shows a clear peak-edge feature at the SC gap energy $\Delta_{s}$. The enhancement of conductivity just outside the gap is due to the accumulation of DOS pushed outside of the gap. Our result is in good agreement with the reported Andreev tunneling experiment [12], which is reproduced here for comparison. In a single gap scenario, it is not clear that the relative contributions of Andreev and single particle tunnelings into the superconductor should change between OD and UD.

The voltage-dependent conductance in high barrier tunneling is plotted in Fig. 4(b) for UD. The Andreev reflection is substantially suppressed, so that the voltage-dependence of $\sigma_{s}$ is similar to that of the DOS [Fig. 1(b)]. In both $\sigma_{s}$ and DOS in the SC phase, there are two energy scales. The lower energy peak is associated with the SC gap $\Delta_{s}$, and the higher energy peak with the RVB gap. The overall profile we obtained is very close to recent STM experimental data on Bi-2212 [39].

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The asymmetry in the YRZ DOS comes from the Dirac quasiparticle at positive energies in the lower quasiparticle band. It is consistent with the recent angle integrated photoemission electron spectroscopy experiments [25] indicating a linear dependence of DOS at the hole level on the hole doping. However, it is much more pronounced than in the tunneling experiments, possibly due to the neglect of the quasiparticle lifetime broadening, which could act to smear signs of a Dirac point at finite energies above the chemical potential. The tunneling conductance in our theory does not include a spectral weight asymmetry upon injecting an electron or a hole in a strongly correlated system [40,41]. Although the long range SC order on the Fermi pockets (or arcs) induces a reduced pairing amplitude also in the antinodal regions through Cooper channel scattering, the corresponding Andreev signal is found to be strongly suppressed.

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In summary, we have studied the tunneling spectroscopy of the underdoped cuprates from the viewpoint of a doped Mott insulator. Our theory semiquantitatively explains the two gap scenario at underdoping. From a broader viewpoint, our calculations support all models in which the pseudogap at underdoping is due to the partial truncation of the Fermi surface through an insulating gap in the antinodal regions, but not due to preformed Cooper pairs.

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[32] “Bare” dispersion from the renormalized mean field theory (see Refs. [15,19]) for the t-J model is used, $e_k = -2t\cos(k_x + k_y) - 4g_s\cos^2(k_x) - 2g_t\cos(k_x + k_y) - \mu$ with $c_{\alpha\sigma} = \cos \alpha c_{\sigma\uparrow} / \sqrt{2}$ and parameters $t = (g_t + \frac{1}{2} g_s J k_B)$, $t' = -0.4$, $t'' = 0.2$, $J = 0.3$ (in units of $t_0$), $c_{\sigma\uparrow} = 0.338$, $c_{\sigma\downarrow} = 4/(1 + x)^2$.
[37] In the high barrier limit, the scattering center has a constant tunneling channel at all energies.